



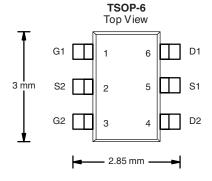
Dual P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)	
- 20	0.200 at $V_{GS} = -4.5 \text{ V}$	± 1.8	
	0.235 at V _{GS} = - 3.6 V	± 1.6	
	0.340 at V _{GS} = - 2.5 V	± 1.3	

FEATURES

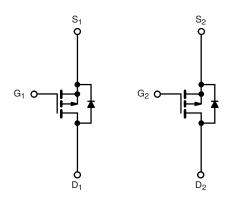
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs: 2.5 V Rated
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si3909DV-T1-E3 (Lead (Pb)-free)

Si3909DV-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	ss otherwise no	ted	
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 20	
Gate-Source Voltage		V _{GS}	± 12	V
Continuous Drain Current (T _J = 150 °C) ^{a, b}	T _A = 25 °C	-	± 1.8	
	T _A = 70 °C	I _D	± 1.2	
Pulsed Drain Current		I _{DM}	± 7	A
Continuous Diode Current (Diode Conduction) ^{a, b}		I _S	- 1.05	
Maximum Power Dissipation ^{a, b}	T _A = 25 °C	D	1.15	10/
	T _A = 70 °C	P _D	0.73	W
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Marrian una lungation to Ambienta	t ≤ 5 s	- R _{thJA}	93	110	°C/W
Maximum Junction-to-Ambient ^a	Steady State		130	150	
Maximum Junction-to-Lead	Steady State		75	90	

Notes:

a. Surface Mounted on FR4 board.

 $b.\ t \leq 5\ s.$

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.5			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 16 V, V _{GS} = 0 V	V _{DS} = - 16 V, V _{GS} = 0 V		- 1	μΑ	
		V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 55 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le$ - 5 V, V_{GS} = - 4.5 V	- 5			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -1.8 \text{ A}$		0.160	0.200	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -3.6 \text{ V}, I_D = -1.6 \text{ A}$		0.190	0.235		
		V _{GS} = - 2.5 V, I _D = - 1 A		0.280	0.340		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 1.8 A		3.6		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.05 A, V _{GS} = 0 V		- 0.83	- 1.1	V	
Dynamic ^b				•			
Total Gate Charge	Q_g			2.7	4.0		
Gate-Source Charge	Q_{gs}	Q_{gs} $V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_D = -1.8 \text{ A}$		0.4		nC	
Gate-Drain Charge	Q_{gd}			0.6			
Turn-On Delay Time	t _{d(on)}			11	17		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		34	50		
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 4.5 V, R_g = 6 Ω		19	30	ns	
Fall Time	t _f			24	36		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.05 A, dI/dt = 100 A/μs		20	40		

Notes:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

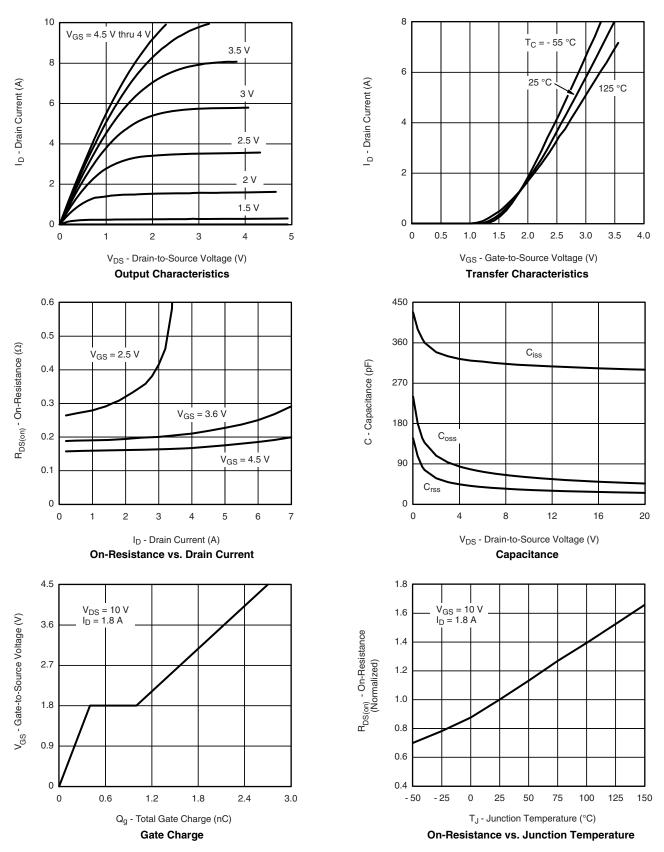
b. Guaranteed by design, not subject to production testing.







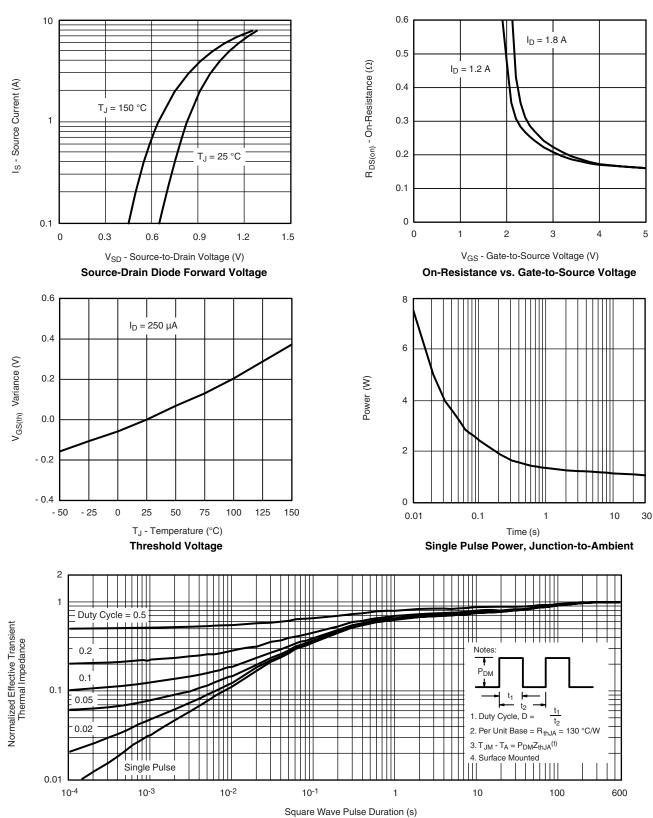
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

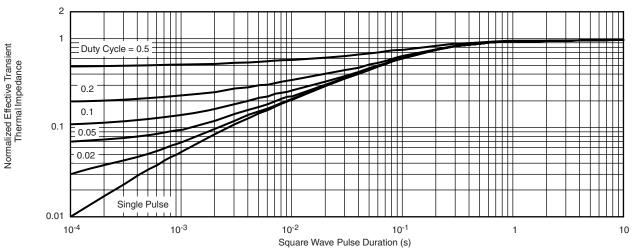


Normalized Thermal Transient Impedance, Junction-to-Ambient



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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